

July 2010

# **SS8050 NPN Epitaxial Silicon Transistor**

### **Features**

- 2W Output Amplifier of Portable Radios in Class B Push-pull Operation.
- · Complimentary to SS8550
- Collector Current: I<sub>C</sub>=1.5A
- Collector Power Dissipation: P<sub>C</sub>=2W (T<sub>C</sub>=25°C)



## **Absolute Maximum Ratings** $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current	1.5	Α
P <sub>C</sub>	Collector Power Dissipation	1	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C

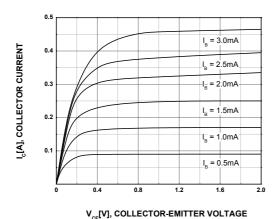
## **Electrical Characteristics** $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =2mA, I <sub>B</sub> =0	25			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	6			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =35V, $I_{E}$ =0			100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =6V, I <sub>C</sub> =0			100	nA
h <sub>FE1</sub> h <sub>FE2</sub> h <sub>FE3</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =5mA V <sub>CE</sub> =1V, I <sub>C</sub> =100mA V <sub>CE</sub> =1V, I <sub>C</sub> =800mA	45 85 40		300	
V <sub>CE (sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> =800mA, I <sub>B</sub> =80mA			0.5	V
V <sub>BE (sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> =800mA, I <sub>B</sub> =80mA			1.2	V
V <sub>BE (on)</sub>	Base-Emitter On Voltage	V <sub>CE</sub> =1V, I <sub>C</sub> =10mA			1	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		9.0		pF
$f_T$	Current Gain Bandwidth Product	V <sub>CE</sub> =10V, I <sub>C</sub> =50mA	100			MHz

## **h**<sub>FE</sub> Classification

Classification	В	С	D
h <sub>FE2</sub>	85 ~ 160	120 ~ 200	160 ~ 300

## **Typical Performance Characteristics**



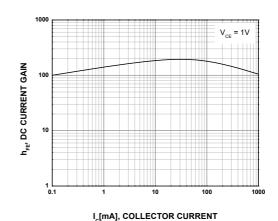


Figure 2. DC current Gain

Figure 1. Static Characteristic

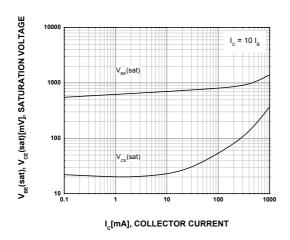


Figure 3. Base-Emitter Saturation Voltage **Collector-Emitter Saturation Voltage** 

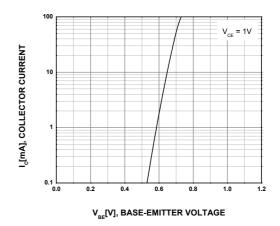


Figure 4. Base-Emitter On Voltage

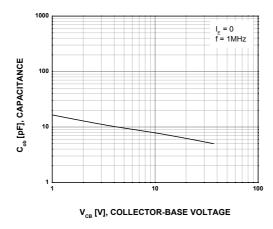


Figure 5. Collector Output Capacitance

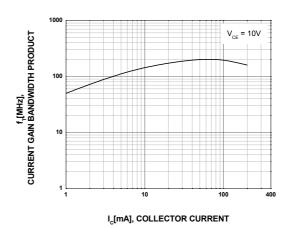
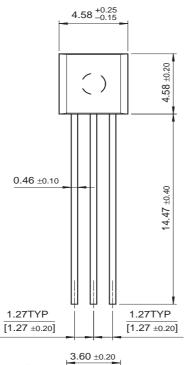
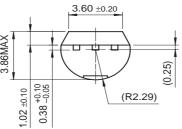


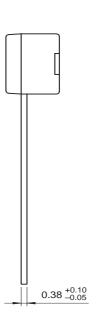
Figure 6. Current Gain Bandwidth Product

## **Physical Dimensions**

TO-92







Dimensions in Millimeters





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